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Signature

DIPLOMA EXAMINATION IN ENGINEERING/TECHNOLOGY/ MANAGEMENT/COMMERCIAL PRACTICE — OCTOBER, 2019

BASIC ELECTRONICS

[*Time* : 3 hours

Marks

 $(5 \times 2 = 10)$

(Maximum marks : 100)

PART — A

(Maximum marks : 10)

I Answer *all* questions in one or two sentences. Each question carries 2 marks.

1. Write any two specifications of a resistor.

2. Sketch the V-I characteristics of zener diode.

3. State the importance of peak inverse voltage.

4. Write the significance of the arrow head in the symbol of a transistor.

5. List the uses of capacitors.

PART — B

(Maximum marks : 30)

II Answer any five of the following questions. Each question carries 6 marks.

1. Describe the charging and discharging of capacitor.

2. Define drift and diffusion current.

3. With suitable diagram explain the working of a half wave rectifier.

4. Explain with diagram the constructional details of a PNP transistor.

5. Draw the symbol and explain the working of a varactor diode.

6. Define the terms rectification efficiency and ripple factor.

7. Draw the output characteristics of CE configuration and mark the three regions of operation.

 $(5 \times 6 = 30)$



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PART - C

(Maximum marks : 60)

(Answer one full question from each unit. Each full question carries 15 marks.)

Unit — I

- III (a) Explain the colour coding of resistors with example and figure.
 - (b) With diagram explain the working principle of transformer.

Or

- IV (a) Define self inductance and mutual inductance.
 - (b) Derive the effective capacitance of series and parallel combination of capacitors.

Unit — II

V (a) Explain with diagram the formation of PN junction and depletion region.

(b) Describe zener and avalanche break down.

Or

- VI (a) Define doping. Explain the formation of N-type semiconductor.
 - (b) Sketch and explain the V-I characteristics of diode.
 - Unit III

VII (a) With circuit diagram and waveform explain the working of full wave bridge rectifier.	10
(ł	b) Explain the working of negative clamper.	5
	OR	

- VIII (a) Explain the working of full wave voltage doubler.
 - (b) Explain the working of shunt capacitor filter.

Unit — IV

- IX (a) State the effect of temperature in leakage current of transistor.
 - (b) Explain the working principle of NPN transistor with suitable diagram.

Or

- X (a) Derive the relation between α , β and γ .
 - (b) Draw the circuit diagram, input and output characteristics of transistor in CB configuration.

Marks

8

7

8

7

9

6

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8 7

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